

# P H Soni

## List of Publications by Year in descending order

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Version: 2024-02-01

10

papers

38

citations

2258059

3

h-index

1872680

6

g-index

10

all docs

10

docs citations

10

times ranked

27

citing authors

#	ARTICLE	IF	CITATIONS
1	Habit modification in L-arginine doped potassium dihydrogen phosphate crystal growth under applied electric field. AIP Conference Proceedings, 2020, , .	0.4	1
2	Thickness dependent band gap of Bi <sub>2-x</sub> SbxTe <sub>3</sub> (x = 0, 0.05, 0.1) thin films. AIP Conference Proceedings, 2016, , .	0.4	0
3	Vickerâ€™s microhardness of Bi <sub>1-x</sub> Sbx (x=0.05â€“0.30) crystals. Journal of Materials Science, 2009, 44, 3504-3507.	3.7	7
4	CREEP ACTIVATION ENERGY OF FLOW PROCESS IN Sn <sub>0.2</sub> Bi <sub>1.8</sub> Te <sub>3</sub> SINGLE CRYSTALS. Surface Review and Letters, 2004, 11, 443-446.	1.1	1
5	Optical bandgap of Sb <sub>0.2</sub> Bi <sub>1.8</sub> Te <sub>3</sub> thin films. Journal of Materials Science, 2003, 38, 1931-1932.	3.7	2
6	Optical band gap of Sn <sub>0.2</sub> Bi <sub>1.8</sub> Te <sub>3</sub> thin films. Bulletin of Materials Science, 2003, 26, 683-684.	1.7	12
7	EFFECT OF ION BEAM IRRADIATION ON HARDNESS OF POLYETHYLENE TEREPHTHALATE. Journal of Macromolecular Science - Pure and Applied Chemistry, 2002, 39, 231-235.	2.2	3
8	GROWTH AND DISLOCATION ETCHING OF Sb <sub>0.2</sub> Bi <sub>1.8</sub> Te <sub>3</sub> SINGLE CRYSTALS. Surface Review and Letters, 1999, 06, 177-181.	1.1	2
9	Effects of anisotropy and annealing on microhardness of In x Bi <sub>2-x</sub> Te <sub>3</sub> (x=0.1 to 0.5) single crystals. Bulletin of Materials Science, 1999, 22, 15-16.	1.7	3
10	Creep activation energy of flow process in Bi <sub>2</sub> Te <sub>2.8</sub> Se <sub>0.2</sub> single crystals. Bulletin of Materials Science, 1999, 22, 21-23.	1.7	7